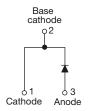


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High Performance Schottky Rectifier, 7.5 A





TO-220AC 2L

PRIMARY CHARACTERISTICS								
I _{F(AV)}	7.5 A							
V_R	35 V, 45 V							
V _F at I _F	0.57 V							
I _{RM} max.	15 mA at 125 °C							
T _J max.	150 °C							
E _{AS}	7 mJ							
Package	2L TO-220AC							
Circuit configuration	Single							

FEATURES

- 150 °C T_J operation
- · High frequency operation
- · Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBR7... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES								
I _{F(AV)}	Rectangular waveform	7.5	А					
V _{RRM}		35/45	V					
I _{FSM}	t _p = 5 μs sine	690	А					
V _F	7.5 A _{pk} , T _J = 125 °C	0.57	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBR735-M3	VS-MBR745-M3	UNITS					
Maximum DC reverse voltage	V_{R}	35	45	V					
Maximum working peak reverse voltage	V_{RWM}	33	45	V					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CON	VALUES	UNITS					
Maximum average forward current	I _{F(AV)}	T _C = 131 °C, rated V _R	7.5	Α					
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	690	А				
		Surge applied at rated load c single phase 60 Hz	150						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 3.5 ^{\circ}$	7	mJ					
Repetitive avalanche current	I _{AR}	Current decaying linearly to Frequency limited by T _J max	2	Α					



VS-MBR735-M3, VS-MBR745-M3

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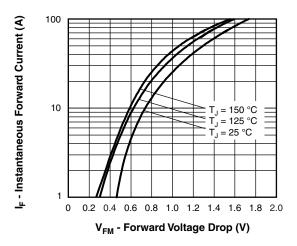
ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
		15 A	T _J = 25 °C	0.84				
Maximum forward voltage drop	V _{FM} (1)	7.5 A	T 105 °C	0.57	V			
		15 A	T _J = 125 °C	0.72				
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.1	mA			
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	15				
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal rang	400	pF				
Typical series inductance	L _S	Measured from top of term	8.0	nΗ				
Maximum voltage rate of change	dV/dt	Rated V _R	1000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction temperature range	TJ		-65 to +150	°C					
Maximum storage temperature range	T _{Stg}		-65 to +175	10					
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	3.0	°C/W					
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50						
Approximate weight			2	g					
Approximate weight			0.07	OZ.					
Mounting torque minimum			6 (5)	kgf · cm					
maximum			12 (10)	(lbf ⋅ in)					
Marking device		Casa style 2L TO 220AC	MBR735						
ivial killy device		Case style 2L TO-220AC		MBR745					

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100 T₁ = 150 °C I_R - Reverse Current (mA) 10 $T_J = 125 \,^{\circ}C$ $T_J = 100 \, ^{\circ}C$ 0.1 $T_{\rm J} = 75$ 0.01 0.001 $T_{\cdot} = 25$ °C 0.0001 15 20 25 30 40 0 10 45 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

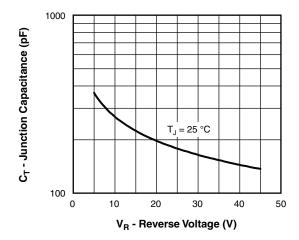


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

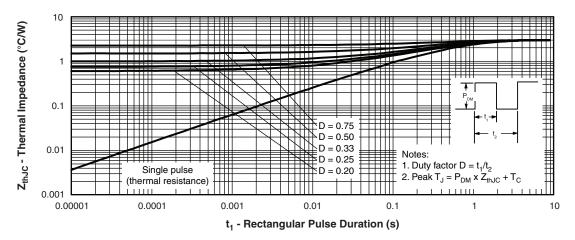


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

Allowable Case Temperature (°C)

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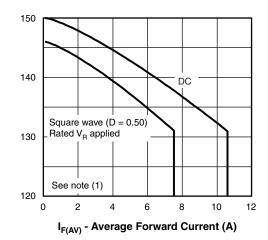


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

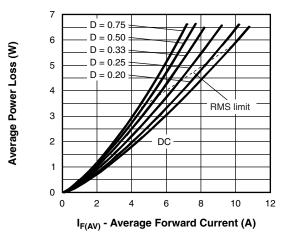


Fig. 6 - Forward Power Loss Characteristics

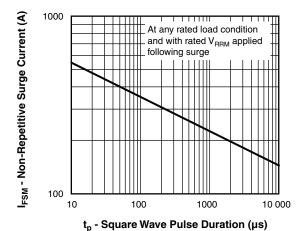


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

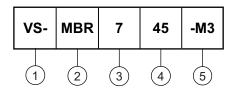
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}$; $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = rated V_R$

VS-MBR735-M3, VS-MBR745-M3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Schottky MBR series

3 - Current rating (7.5 A) 35 = 35 V 4 - Voltage ratings - 45 = 45 V

5 - Environmental digit

-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	PACKAGING DESCRIPTION							
VS-MBR735-M3	50	Antistatic plastic tubes						
VS-MBR745-M3	50	Antistatic plastic tubes						

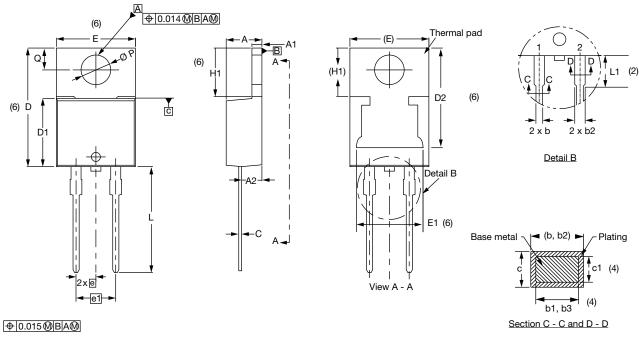
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96156						
Part marking information	www.vishay.com/doc?95391						
SPICE model	www.vishay.com/doc?95298						



Vishay Semiconductors

TO-220AC 2L

DIMENSIONS in millimeters and inches



Lead tip

Conforms to JEDEC® outline TO-220AC

SYMBOL	MILLIMETERS		INC	NOTES		SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355							•	

Notes

- $^{(1)}$ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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